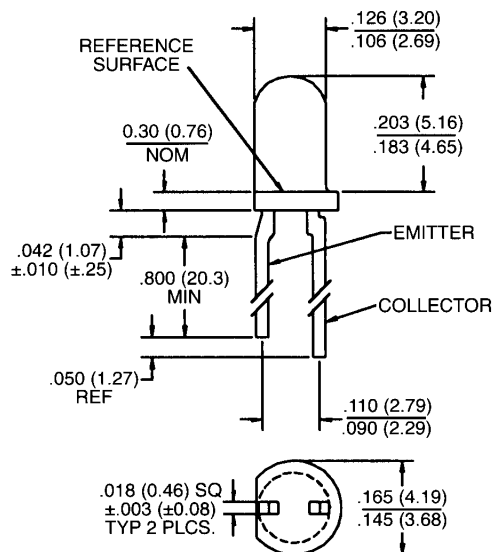




PLASTIC SILICON PHOTOTRANSISTOR

QSC112/113/114

PACKAGE DIMENSIONS



ST2142

NOTES:

1. DIMENSIONS ARE IN INCHES (mm).
2. TOLERANCE IS ±.010 (.25) UNLESS OTHERWISE SPECIFIED.
3. FLAT DENOTES CATHODE.

DESCRIPTION

The QSC11X is a silicon phototransistor encapsulated in an infrared transparent, black T-1 package.

FEATURES

- Tight production distribution.
- Steel lead frames for improved reliability in solder mounting.
- Good optical-to-mechanical alignment.
- Plastic package is infrared transparent black to attenuate visible light.
- Mechanically and spectrally matched to the QECXXX LED.
- Black plastic body allows easy recognition from LED.



PLASTIC SILICON PHOTOTRANSISTOR

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

| | |
|-------------------------------------|---------------------------------------|
| Storage Temperature | -40°C to +100°C |
| Operating Temperature | -40°C to +100°C |
| Soldering: | |
| Lead Temperature (Iron) | 240°C for 5 sec. ^(2,3,4,5) |
| Lead Temperature (Flow) | 260°C for 10 sec. ^(2,3,5) |
| Collector-Emitter Breakdown Voltage | 30 Volts |
| Emitter-Collector Breakdown Voltage | 5.0 Volts |
| Power Dissipation | 100 mW ⁽¹⁾ |

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified) (All measurements made under pulse conditions.)

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|------------------------------------|---------------|------|---------|------|---------------|---|
| Collector-Emitter Breakdown | BV_{CEO} | 30 | — | — | V | $I_C = 1.0 \text{ mA}$ |
| Emitter-Collector Breakdown | BV_{ECO} | 5.0 | — | — | V | $I_E = 100 \mu\text{A}$ |
| Collector-Emitter Leakage | I_{CEO} | — | — | 100 | nA | $V_{CE} = 10 \text{ V}$ |
| Reception Angle at 1/2 Sensitivity | θ | — | ± 8 | — | Degrees | |
| On-State Collector Current QSC112 | $I_{C(ON)}$ | 1.0 | — | 4.0 | mA | $E_e = 0.5 \text{ mW/cm}^2, V_{CE} = 5\text{V}^{(6)}$ |
| On-State Collector Current QSC113 | $I_{C(ON)}$ | 2.4 | — | 9.6 | mA | $E_e = 0.5 \text{ mW/cm}^2, V_{CE} = 5\text{V}^{(6)}$ |
| On-State Collector Current QSC114 | $I_{C(ON)}$ | 4.0 | — | — | mA | $E_e = 0.5 \text{ mW/cm}^2, V_{CE} = 5\text{V}^{(6)}$ |
| Rise Time | t_r | — | 5.0 | — | μS | $I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100\Omega$ |
| Fall Time | t_f | — | 5.0 | — | μS | $I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100\Omega$ |
| Saturation Voltage | $V_{CE(SAT)}$ | — | — | 0.40 | V | $I_C = 0.50 \text{ mA}, E_e = 0.5 \text{ mW/cm}^2^{(6)}$ |

NOTES

1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
2. RMA flux is recommended.
3. Methanol or Isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron tip 1/16" (1.6 mm) minimum from housing.
5. As long as leads are not under any stress or spring tension.
6. Light source is an AlGaAs LED emitting light at a peak wavelength of 880 nm.